

## TL331B、TL391B 和 TL331 单路比较器

### 1 特性

- 全新 [TL331B](#) 和 [TL391B](#)
- 改进了 B 版本的规格
  - 最大额定值：高达 38V
  - ESD 等级 (HBM)：2kV
  - 提高了反向电压性能
  - 低输入失调电压：0.37mV
  - 低输入偏置电流：3.5nA
  - 低电源电流：430μA
  - 更短的响应时间 (1μs)
  - [TL391B](#) 提供了 [替代引脚排列](#)
- TL331B 是经改进的 TL331 直接替代产品
- 共模输入电压范围包括接地
- 差分输入电压范围等于最大额定电源电压：±38V
- 低输出饱和电压
- 输出与 TTL、MOS 和 CMOS 兼容

### 2 应用

- [扫地机器人](#)
- [单相 UPS](#)
- [服务器 PSU](#)
- [无线电动工具](#)
- [无线基础设施](#)
- [电器](#)
- [楼宇自动化](#)
- [工厂自动化与控制](#)
- [电机驱动器](#)
- [信息娱乐系统与仪表组](#)

### 3 说明

[TL331B](#) 和 [TL391B](#) 器件是业界通用 [TL331](#) 比较器的下一代版本。下一代器件为成本敏感型应用提供了卓越的价值，其特性包括更低的失调电压、更高的电源电压能力、更低的电源电流、更低的输入偏置电流、更低的传播延迟、更宽的温度范围以及更高的 2kV ESD 性能，并提供了直接替代的便利性。[TL331B](#) 是经改进的 [TL331I](#) 和 [TL331K](#) 版本直接替代产品，而 [TL391B](#) 可提供 [TL331B](#) 的 [替代引脚排列](#)，以替代同类竞争器件。

如果两个电源的电压差处于 2V 至 36V 范围内且 VCC 比输入共模电压至少高 1.5V，那么也可以使用双电源。漏极电流不受电源电压的影响。可将输出连接到其它集电极开路输出，以实现有线 AND 关联。

#### 器件信息

器件型号 <sup>(1)</sup>	封装	本体尺寸 (标称值) <sup>(2)</sup>
TL331、 TL331B、 TL391B	SOT-23 (5)	2.90mm × 1.60mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。

#### 系列比较表

规格	<a href="#">TL331B</a> <a href="#">TL391B</a>	<a href="#">TL331I</a>	<a href="#">TL331K</a>	单位
电源电压	2 至 36	2 至 36	2 至 36	V
总电源电流 (5V 至 36V (最大值))	0.43	0.7	0.7	mA
温度范围	-40 至 125	-40 至 85	-40 至 105	°C
ESD (HBM)	2000	1000	1000	V
偏移电压 (整个温度范围内的最大值)	±4	±9	±9	mV
输入偏置电流 (典型值/最大值)	3.5/25	25/250	25/250	nA
响应时间 (典型值)	1	1.3	1.3	μsec



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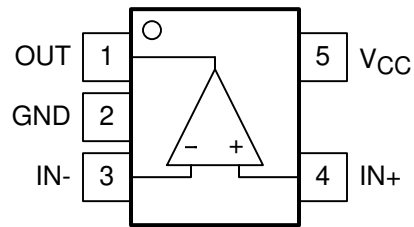
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## 4 Pin Configuration and Functions



Note reversed inputs compared to similar common pinout

图 4-1. TL331, TL331B DBV Package, 5-Pin SOT-23, Top View



Note reversed inputs compared to similar common pinout

图 4-2. TL391B DBV Package, 5-Pin SOT-23, Top View

## Pin Functions

NAME	PIN		TYPE	DESCRIPTION
	TL331, TL331B NO.	TL391B NO.		
IN+	3	4	I	Positive Input
IN -	1	3	I	Negative Input
OUT	4	1	O	Open Collector/Drain Output
V <sub>CC</sub>	5	5	—	Power Supply Input
GND	2	2	—	Ground

## 5 Specifications

### 5.1 Absolute Maximum Ratings, TL331 and TL331K

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>	0	36	V
V <sub>ID</sub>	Differential input voltage <sup>(3)</sup>	- 36	36	V
V <sub>I</sub>	Input voltage range (either input)	- 0.3	36	V
V <sub>O</sub>	Output voltage	0	36	V
I <sub>O</sub>	Output current	0	20	mA
	Duration of output short-circuit to ground <sup>(4)</sup>	Unlimited		
I <sub>IK</sub>	Input current <sup>(5)</sup>		- 50	mA
T <sub>J</sub>	Operating virtual junction temperature	- 40	150	°C
T <sub>stg</sub>	Storage temperature	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the network ground.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V<sub>CC</sub> can cause excessive heating and eventual destruction.
- (5) Input current flows thorough parasitic diode to ground and will turn on parasitic transistors that will increase ICC and may cause output to be incorrect. Normal operation resumes when input current is removed.

### 5.2 Absolute Maximum Ratings, TL331B and TL391B

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>	-0.3	38	V
V <sub>ID</sub>	Differential input voltage <sup>(3)</sup>	- 38	38	V
V <sub>I</sub>	Input voltage range (either input)	- 0.3	38	V
V <sub>O</sub>	Output voltage	-0.3	38	V
I <sub>O</sub>	Output current		20	mA
	Duration of output short-circuit to ground <sup>(4)</sup>	Unlimited		
I <sub>IK</sub>	Input current <sup>(5)</sup>		- 50	mA
T <sub>J</sub>	Operating virtual junction temperature	- 40	150	°C
T <sub>stg</sub>	Storage temperature	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the network ground.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V<sub>CC</sub> can cause excessive heating and eventual destruction.
- (5) Input current flows thorough parasitic diode to ground and will turn on parasitic transistors that will increase ICC and may cause output to be incorrect. Normal operation resumes when input current is removed.

### 5.3 ESD Ratings - TL331B and TL391B

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±750

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 5.4 ESD Ratings, TL331 and TL331K

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±1000
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±750

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 5.5 Recommended Operating Conditions, TL331B and TL391B

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	2	36	V
T <sub>J</sub>	Junction temperature	- 40	125	°C

### 5.6 Recommended Operating Conditions, TL331 and TL331K

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	2	36	V
T <sub>J</sub>	Junction temperature, TL331	- 40	85	°C
T <sub>J</sub>	Junction temperature, TL331K	- 40	105	°C

### 5.7 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TL331x, TL391x	UNIT
		DBV (SOT-23)	
		5 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	211.7	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	133.6	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	79.9	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	56.4	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	79.6	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) report.

### 5.8 Electrical Characteristics, TL331B and TL391B

$V_S = 5V, V_{CM} = (V^-)$ ;  $T_A = 25^\circ C$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage	$V_S = 5$ to 36V	- 2.5	$\pm 0.37$	2.5	mV
		$V_S = 5$ to 36V, $T_A = -40^\circ C$ to $+125^\circ C$	- 4		4	
$I_B$	Input bias current			- 3.5	- 25	nA
		$T_A = -40^\circ C$ to $+125^\circ C$			- 50	nA
$I_{OS}$	Input offset current		- 10	$\pm 0.5$	10	nA
		$T_A = -40^\circ C$ to $+125^\circ C$	- 25		25	nA
$V_{CM}$	Input voltage range	$V_S = 3$ to 36V	$(V^-) - 0.1$		$(V^+) - 1.5$	V
		$V_S = 3$ to 36V, $T_A = -40^\circ C$ to $+125^\circ C$	$(V^-) - 0.05$		$(V^+) - 2.0$	V
$A_{VD}$	Large signal differential voltage amplification	$V_S = 15V, V_O = 1.4V$ to 11.4V; $R_L \geq 15k$ to $(V^+)$	50	200		V/mV
$V_{OL}$	Low level output Voltage {swing from $(V^-)$ }	$I_{SINK} \leq 4mA, V_{ID} = -1V$		110	400	mV
		$I_{SINK} \leq 4mA, V_{ID} = -1V$ $T_A = -40^\circ C$ to $+125^\circ C$			550	mV
$I_{OH-LKG}$	High-level output leakage current	$(V^+) = V_O = 5V; V_{ID} = 1V$		0.1	20	nA
$I_{OH-LKG}$	High-level output leakage current	$(V^+) = V_O = 36V; V_{ID} = 1V; T_A = -40^\circ C$ to $+125^\circ C$			1000	nA
$I_{OL}$	Low level output current	$V_{OL} = 1.5V; V_{ID} = -1V; V_S = 5V$	6	18		mA
$I_Q$	Quiescent current	$V_S = 5V$ , no load		210	330	$\mu A$
		$V_S = 36V$ , no load, $T_A = -40^\circ C$ to $+125^\circ C$		275	430	$\mu A$

### 5.9 Switching Characteristics, TL331B and TL391B

$V_S = 5V, V_O PULLUP = 5V, V_{CM} = V_S/2, C_L = 15pF, R_L = 5.1k$  Ohm,  $T_A = 25^\circ C$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{response}$	Propagation delay time, high-to-low; Small scale input signal <sup>(1)</sup>	Input overdrive = 5mV, Input step = 100mV		1000		ns
$t_{response}$	Propagation delay time, high-to-low; TTL input signal <sup>(1)</sup>	TTL input with $V_{ref} = 1.4V$		300		ns

(1) High-to-low and low-to-high refers to the transition at the input.

## 5.10 Electrical Characteristics, TL331 and TL331K

at specified free-air temperature,  $V_{CC} = 5V$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	$T_A$ <sup>(3)</sup>	MIN	TYP	MAX	UNIT
$V_{IO}$ Input offset voltage	$V_{CC} = 5V$ to $30V$ , $V_O = 1.4V$ , $V_{IC} = V_{IC(min)}$	25°C		2	5	mV
		Full range			9	
$I_{IO}$ Input offset current	$V_O = 1.4V$	25°C		5	50	nA
		Full range			250	
$I_{IB}$ Input bias current	$V_O = 1.4V$	25°C		- 25	- 250	nA
		Full range			- 400	
$V_{ICR}$ Common-mode input voltage range <sup>(2)</sup>		Full range	0 to $V_{CC} - 1.5$			V
$A_{VD}$ Large-signal differential voltage amplification	$V_{CC} = 15V$ , $V_O = 1.4V$ to $11.4V$ , $R_L \geq 15 k\Omega$ to $V_{CC}$	25°C	50	200		V/mV
$I_{OH}$ High-level output current	$V_{OH} = 5V$ , $V_{ID} = 1V$ $V_{OH} = 30V$ , $V_{ID} = 1V$	25°C		0.1	50	nA
		Full range			1	$\mu A$
$V_{OL}$ Low-level output voltage	$I_{OL} = 4mA$ , $V_{ID} = - 1V$	25°C		150	400	mV
		Full range			700	
$I_{OL}$ Low-level output current	$V_{OL} = 1.5V$ , $V_{ID} = - 1V$	25°C	6			mA
$I_{CC}$ Supply current	$R_L = \infty$ , $V_{CC} = 5V$	25°C		0.4	0.7	mA

- (1) All characteristics are measured with zero common-mode input voltage, unless otherwise specified.  
(2) The voltage at either input or common-mode must not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is  $V_{CC+} - 1.5V$ , but either or both inputs can go to 30V without damage.  
(3) Full range  $T_A$  is  $- 40^\circ C$  to  $+85^\circ C$  for I-suffix devices and  $- 40^\circ C$  to  $+105^\circ C$  for K-suffix devices.

## 5.11 Switching Characteristics, TL331 and TL331K

$V_{CC} = 5V$ ,  $T_A = 25^\circ C$

PARAMETER	TEST CONDITIONS	TYP	UNIT	
Response time	$R_L$ connected to 5V through 5.1k $\Omega$ , $C_L = 15pF$ <sup>(1) (2)</sup>	100mV input step with 5mV overdrive	1.3	$\mu s$
		TTL-level input step	0.3	

- (1)  $C_L$  includes probe and jig capacitance.  
(2) The response time specified is the interval between the input step function and the instant when the output crosses 1.4V.

## 5.12 Typical Characteristics

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.



图 5-1. Supply Current vs. Supply Voltage



图 5-2. Total Supply Current vs. Input Voltage at 3V

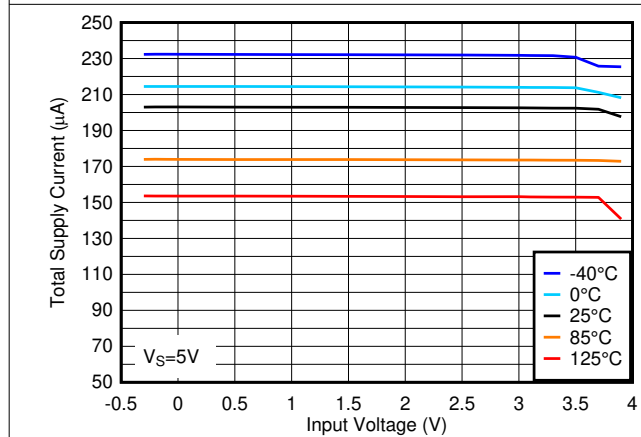


图 5-3. Total Supply Current vs. Input Voltage at 3.3V

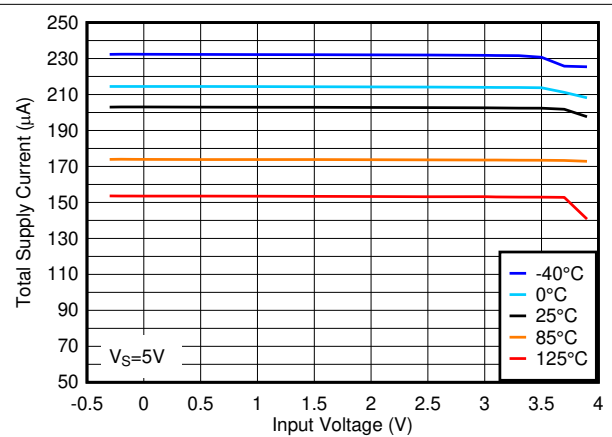


图 5-4. Total Supply Current vs. Input Voltage at 5V

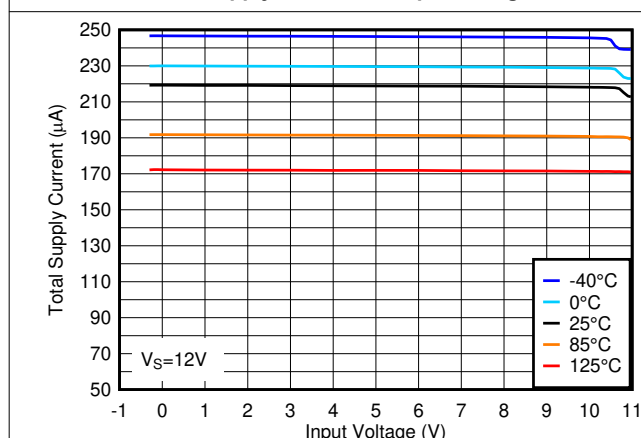


图 5-5. Total Supply Current vs. Input Voltage at 12V

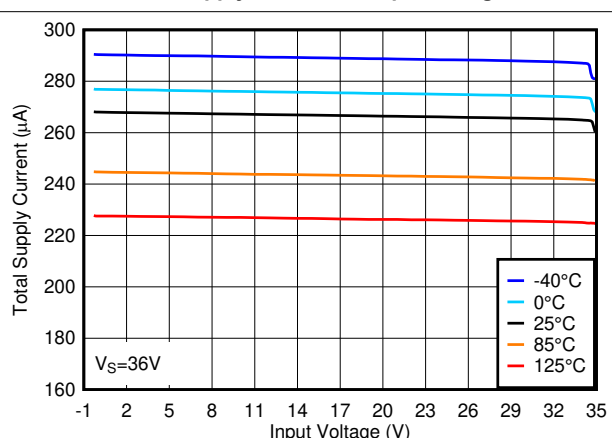


图 5-6. Total Supply Current vs. Input Voltage at 36V

### 5.12 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.

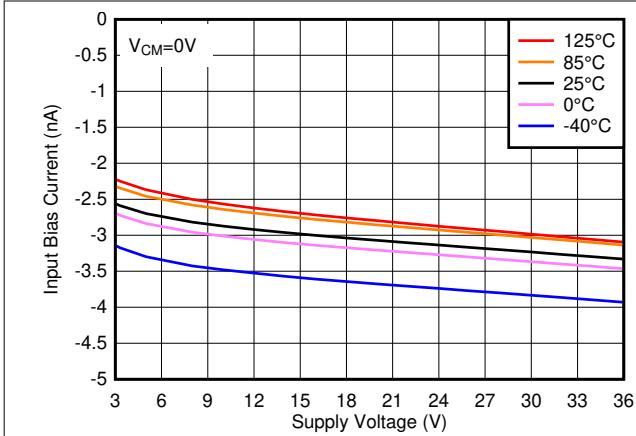


图 5-7. Input Bias Current vs. Supply Voltage

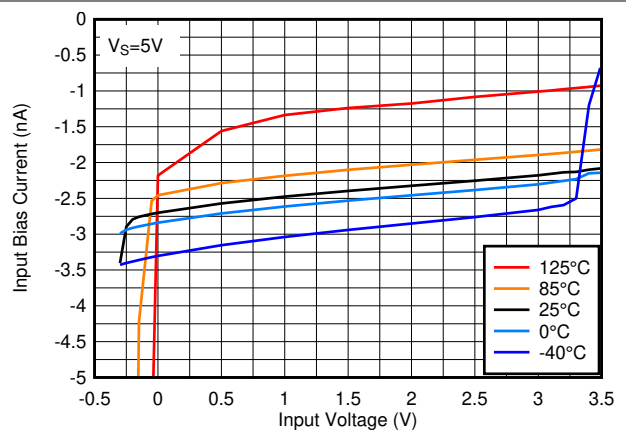


图 5-8. Input Bias Current vs. Input Voltage at 5V



图 5-9. Input Bias Current vs. Input Voltage at 12V

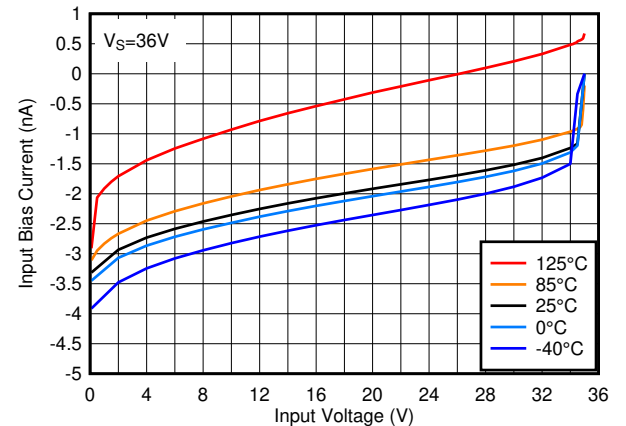


图 5-10. Input Bias Current vs. Input Voltage at 36V



图 5-11. Input Offset Voltage vs. Supply Voltage at  $-40^\circ\text{C}$

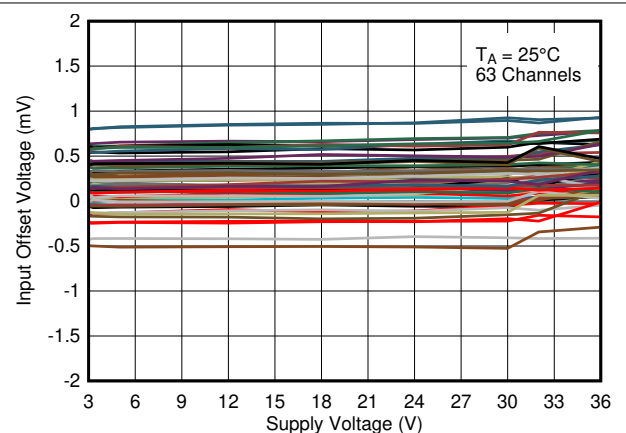


图 5-12. Input Offset Voltage vs. Supply Voltage at  $25^\circ\text{C}$

### 5.12 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.



图 5-13. Input Offset Voltage vs. Supply Voltage at 85°C

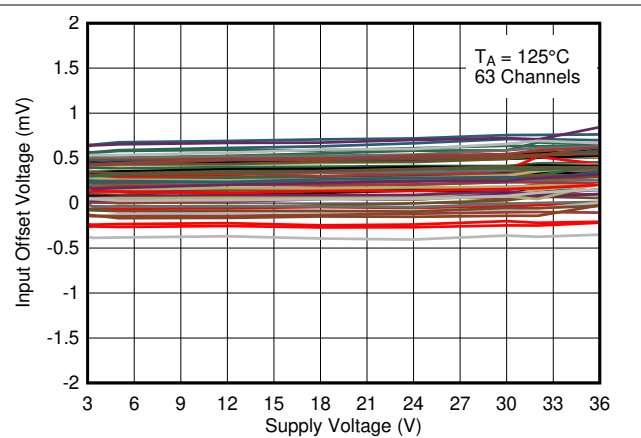


图 5-14. Input Offset Voltage vs. Supply Voltage at 125°C

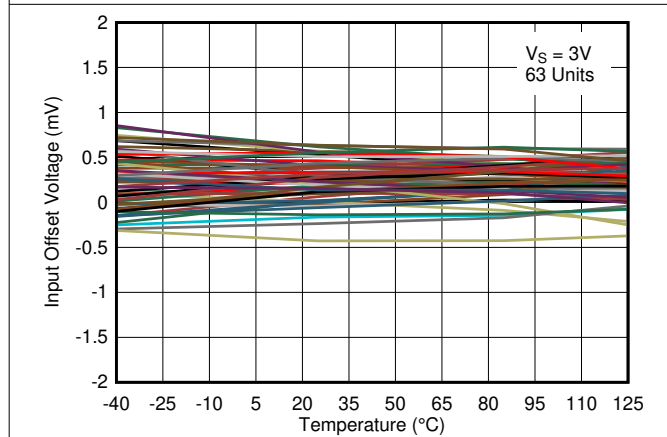


图 5-15. Input Offset Voltage vs. Temperature at 3V

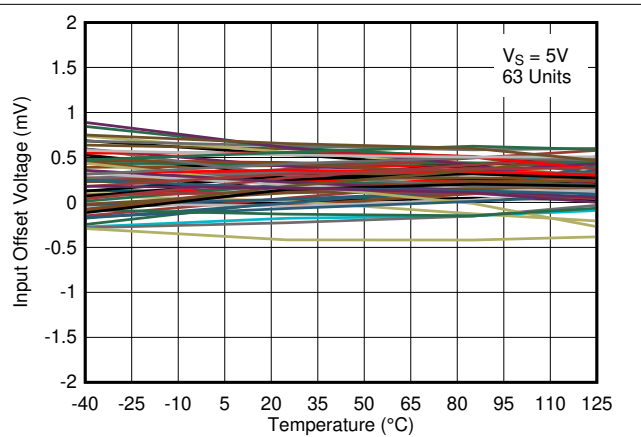


图 5-16. Input Offset Voltage vs. Temperature at 5V

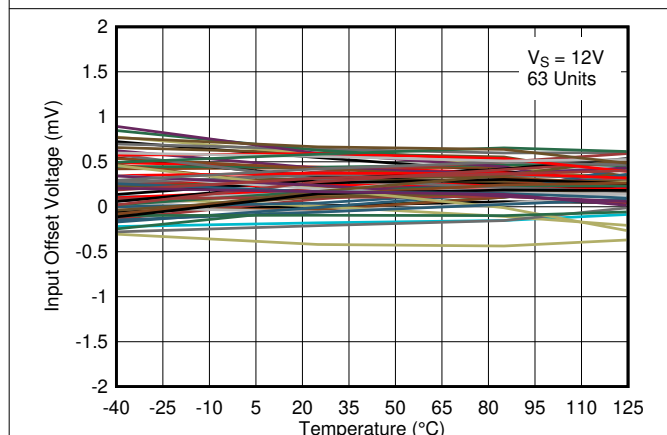


图 5-17. Input Offset Voltage vs. Temperature at 12V

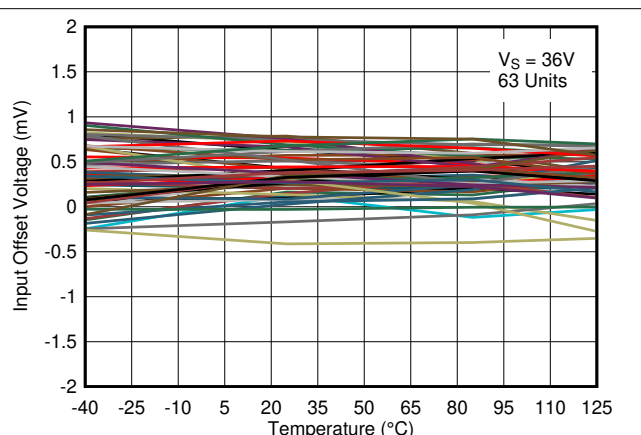


图 5-18. Input Offset Voltage vs. Temperature at 36V

### 5.12 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.



图 5-19. Output Low Voltage vs. Output Sinking Current at 3V



图 5-20. Output Low Voltage vs. Output Sinking Current at 5V

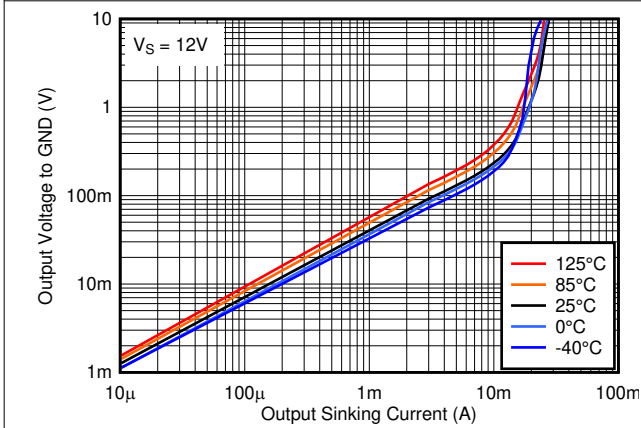


图 5-21. Output Low Voltage vs. Output Sinking Current at 12V

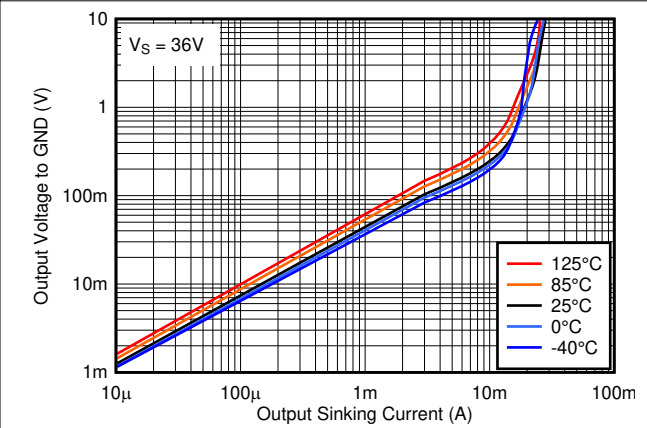


图 5-22. Output Low Voltage vs. Output Sinking Current at 36V

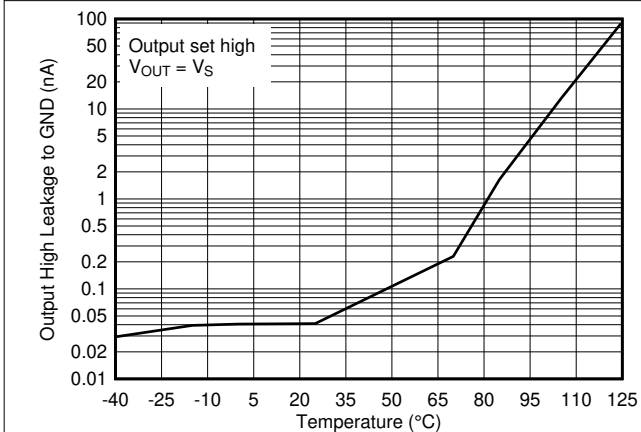


图 5-23. Output High Leakage Current vs. Temperature at 5V

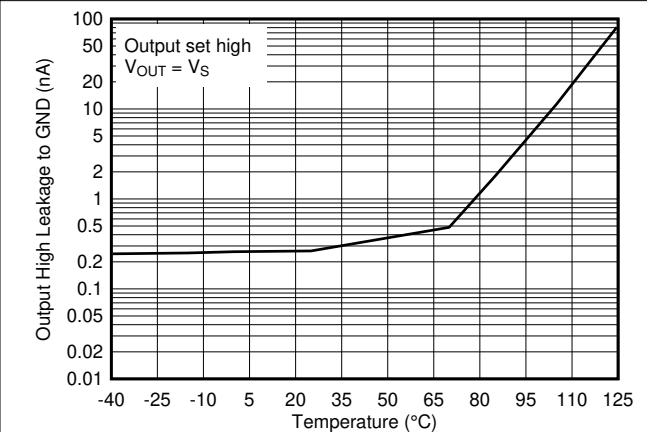


图 5-24. Output High Leakage Current vs. Temperature at 36V

### 5.12 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.

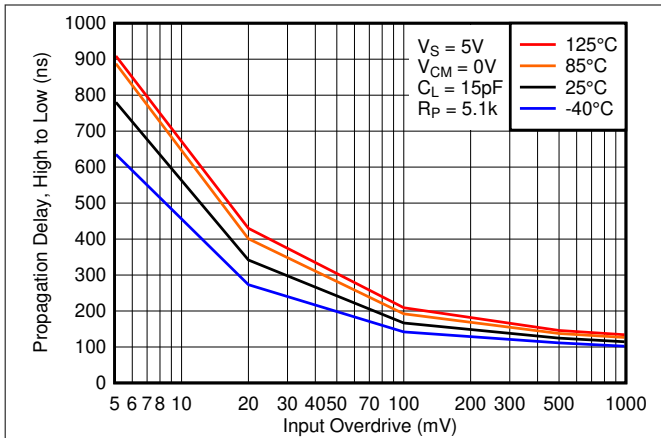


图 5-25. High to Low Propagation Delay vs. Input Overdrive Voltage, 5V

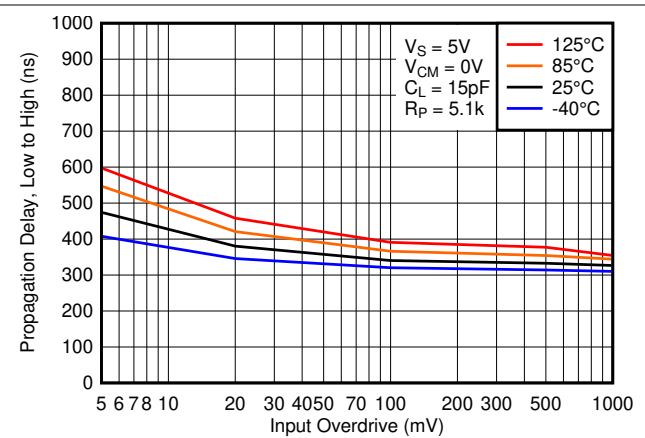


图 5-26. Low to High Propagation Delay vs. Input Overdrive Voltage, 5V

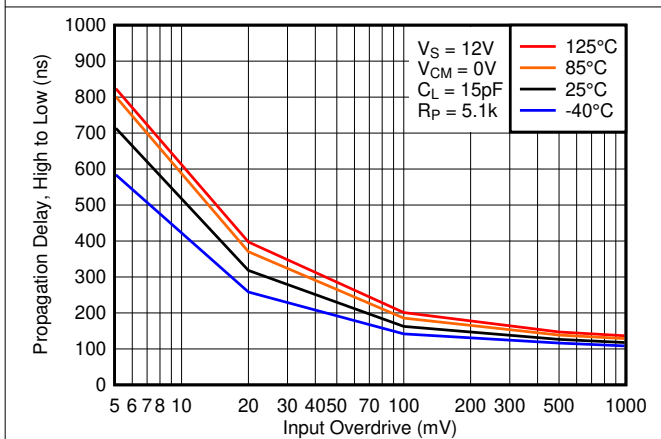


图 5-27. High to Low Propagation Delay vs. Input Overdrive Voltage, 12V

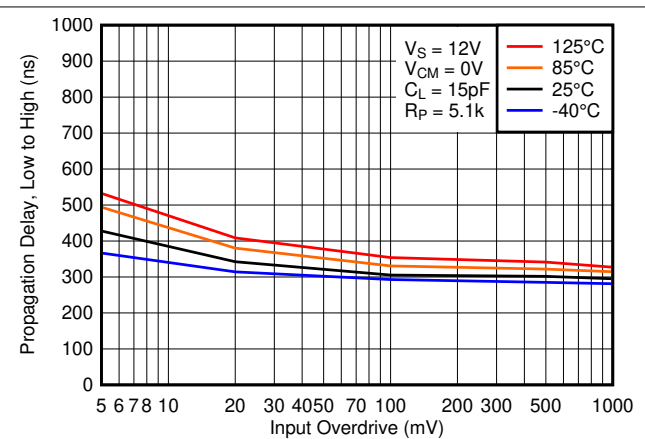


图 5-28. Low to High Propagation Delay vs. Input Overdrive Voltage, 12V

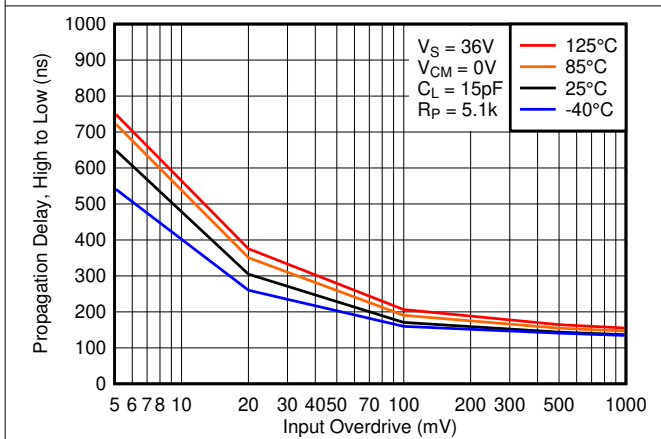


图 5-29. High to Low Propagation Delay vs. Input Overdrive Voltage, 36V

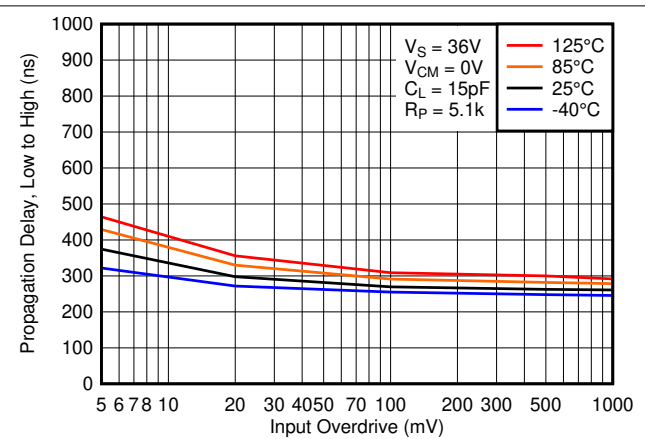
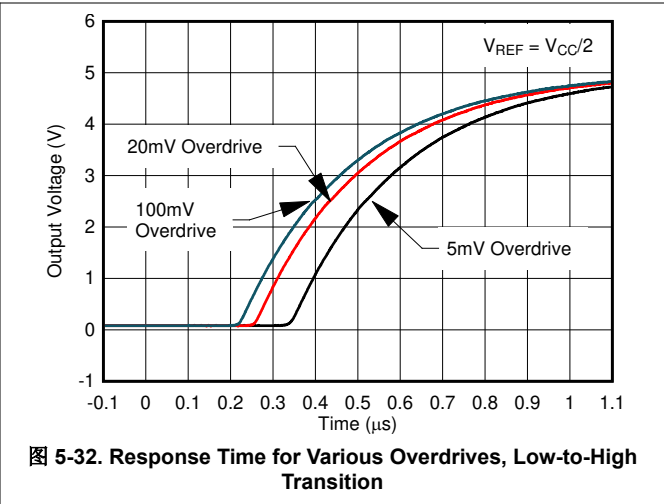
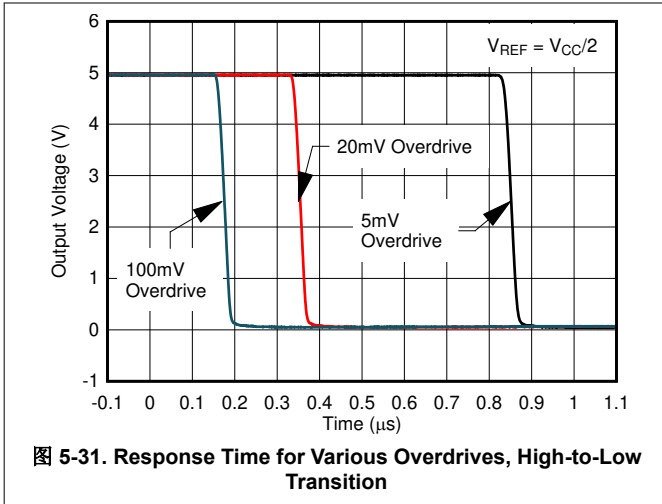


图 5-30. Low to High Propagation Delay vs. Input Overdrive Voltage, 36V

### 5.12 Typical Characteristics (continued)

$T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $R_{\text{PULLUP}} = 5.1\text{k}$ ,  $C_L = 15\text{pF}$ ,  $V_{\text{CM}} = 0\text{V}$ ,  $V_{\text{UNDERDRIVE}} = 100\text{mV}$ ,  $V_{\text{OVERDRIVE}} = 100\text{mV}$  unless otherwise noted.



## 6 Detailed Description

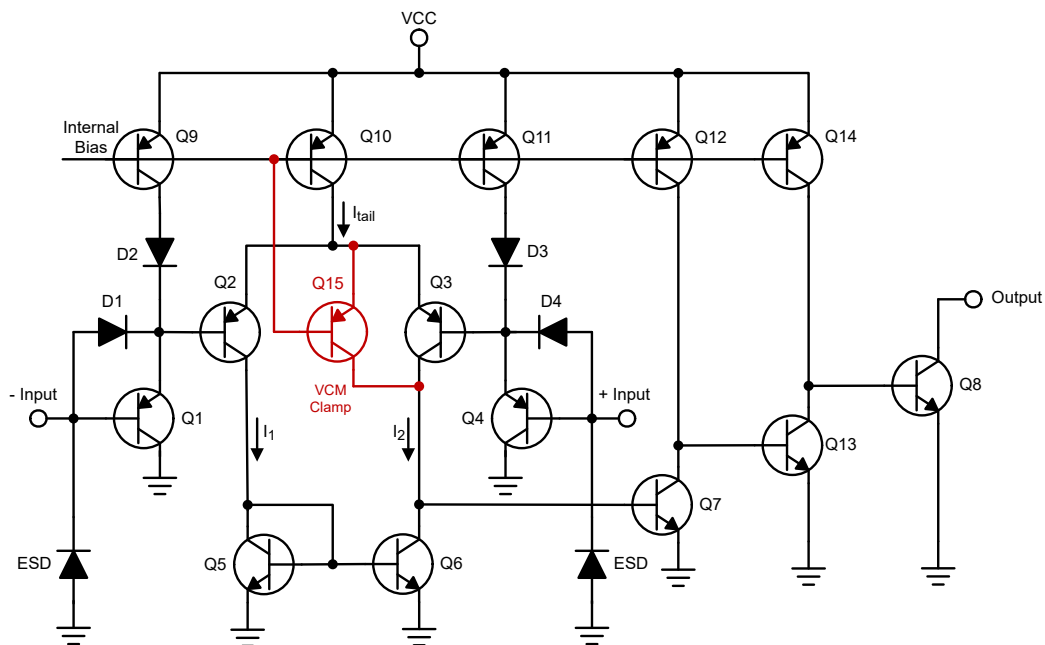
### 6.1 Overview

The TL331 family is a single comparator with the ability to operate up to 36V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications. This is due to its very wide supply voltages range (2V to 36V), low  $I_q$ , and fast response.

The open-collector output allows the user to configure the output's logic low voltage ( $V_{OL}$ ) and can be utilized to enable the comparator to be used in AND functionality.

The TL331B and TL391B are performance upgrades to standard TL331 using the latest process technologies allowing for lower offset voltages, lower input bias and supply currents and faster response time over an extended temperature range. The TL331B can drop-in replace the "I" or "K" versions of TL331. The TL391B is an alternate pinout for replacing competitive devices.

### 6.2 Functional Block Diagram



### 6.3 Feature Description

TL331x family consists of a PNP Darlington pair input, allowing the device to operate with very high gain and fast response with minimal input bias current. The input Darlington pair creates a limit on the input common mode voltage capability, allowing TL331x to accurately function from ground to  $V_{CC} - 1.5V$  differential input. In later revisions, a clamp was added around Q3 to mimic the outside-of-input voltage range behavior of the original classic silicon.

The output consists of an open collector NPN (pull-down or low side) transistor. The output NPN will sink current when the negative input voltage is higher than the positive input voltage and the offset voltage. The  $V_{OL}$  is resistive and will scale with the output current. Please see the "Output Low Voltage vs. Output Sinking Current" graphs in [Typical Characteristics](#) for  $V_{OL}$  values with respect to the output current.

### 6.4 Device Functional Modes

#### 6.4.1 Voltage Comparison

The TL331x operates solely as a voltage comparator, comparing the differential voltage between the positive and negative pins and outputting a logic low or high impedance (logic high with pull-up) based on the input differential polarity.

## 7 Application and Implementation

### 备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 7.1 Application Information

TL331x will typically be used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output to drive the comparison logic output to a logic voltage level to an MCU or logic device. The wide supply range and high voltage capability makes TL331x optimal for level shifting to a higher or lower voltage.

### 7.2 Typical Application

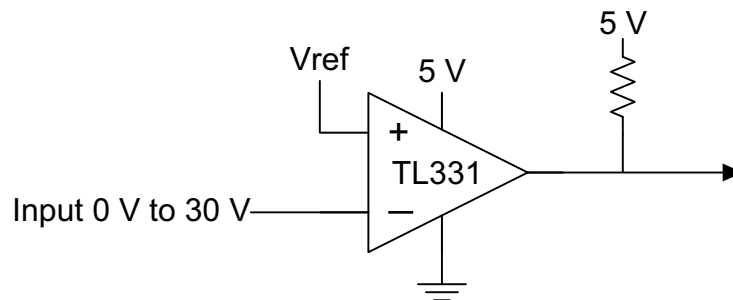


图 7-1. Typical Application Schematic

#### 7.2.1 Design Requirements

For this design example, use the parameters listed in 表 7-1 as the input parameters.

表 7-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0V to $V_{CC} - 1.5V$
Supply Voltage	2V to 36V
Logic Supply Voltage ( $R_{PULLUP}$ Voltage)	2V to 36V
Output Current ( $V_{LOGIC}/R_{PULLUP}$ )	1 $\mu$ A to 4mA
Input Overdrive Voltage	100mV
Reference Voltage	2.5V
Load Capacitance ( $C_L$ )	15pF

#### 7.2.2 Detailed Design Procedure

When using TL331x in a general comparator application, determine the following:

- Input voltage range
- Minimum overdrive voltage
- Output and drive current
- Response time

### 7.2.2.1 Input Voltage Range

When choosing the input voltage range, the input common mode voltage range ( $V_{ICR}$ ) must be taken in to account. If temperature operation is above or below 25°C the  $V_{ICR}$  can range from 0V to  $V_{CC} - 1.5V$ . This limits the input voltage range to as high as  $V_{CC} - 1.5V$  and as low as 0V. Operation outside of this range can yield incorrect comparisons.

Below is a list of input voltage situation and their outcomes:

1. When both IN- and IN+ are both within the common mode range:
  - a. If IN- is higher than IN+ and the offset voltage, the output is low and the output transistor is sinking current
  - b. If IN- is lower than IN+ and the offset voltage, the output is high impedance and the output transistor is not conducting
2. When IN- is higher than common mode and IN+ is within common mode, the output is low and the output transistor is sinking current
3. When IN+ is higher than common mode and IN- is within common mode, the output is high impedance and the output transistor is not conducting
4. When IN- and IN+ are both higher than common mode, please see the *Both Inputs Above Input Range Behavior* section of the [LM339 Family Application Note \(SNOAA35\)](#).

### 7.2.2.2 Minimum Overdrive Voltage

Overdrive Voltage is the differential voltage produced between the positive and negative inputs of the comparator over the offset voltage ( $V_{IO}$ ). To make an accurate comparison the Overdrive Voltage ( $V_{OD}$ ) should be higher than the input offset voltage ( $V_{IO}$ ). Overdrive voltage can also determine the response time of the comparator, with the response time decreasing with increasing overdrive. [图 7-2](#) and [图 7-3](#) show positive and negative response times with respect to overdrive voltage.

### 7.2.2.3 Output and Drive Current

Output current is determined by the load/pull-up resistance and logic/pull-up voltage. The output current produces a output low voltage ( $V_{OL}$ ) from the comparator. In which  $V_{OL}$  is proportional to the output current. Use *Output Low Voltage vs Output Current ( $I_{OL}$ )* to determine  $V_{OL}$  based on the output current.

The output current can also effect the transient response. More is explained in the next section.

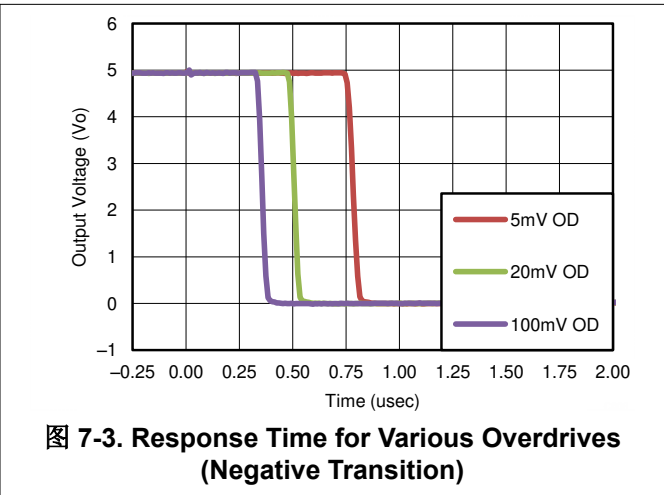
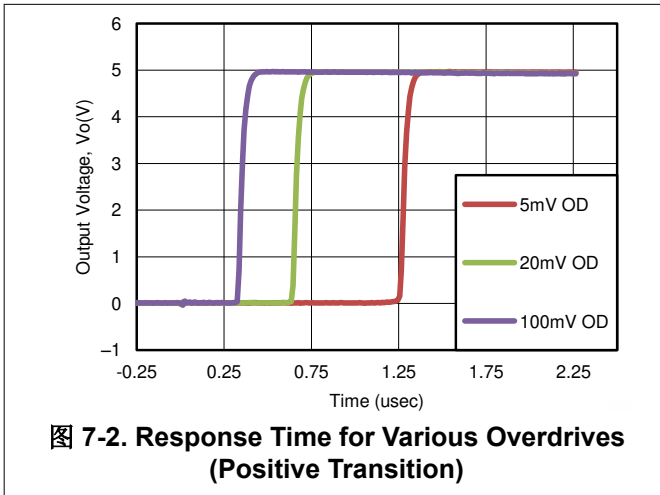
### 7.2.2.4 Response Time

Response time is a function of input over drive. See [节 7.2.3](#) for typical response times. The rise and fall times can be determined by the load capacitance ( $C_L$ ), load/pullup resistance ( $R_{PULLUP}$ ), and equivalent collector-emitter resistance ( $R_{CE}$ ).

- The rise time ( $\tau_R$ ) is approximately  $\tau_R \sim R_{PULLUP} \times C_L$
- The fall time ( $\tau_F$ ) is approximately  $\tau_F \sim R_{CE} \times C_L$ 
  - $R_{CE}$  can be determined by taking the slope of *Output Low Voltage vs Output Current ( $I_{OL}$ )* in its linear region at the desired temperature, or by dividing the  $V_{OL}$  by  $I_{out}$

### 7.2.3 Application Curves

The following curves were generated with 5V on  $V_{CC}$  and  $V_{Logic}$ ,  $R_{PULLUP} = 5.1k\Omega$ , and 50pF scope probe.



### 7.2.4 ESD Protection

The "B" and TiB versions add dedicated ESD protections on all the pins for improved ESD performance. Please see Application Note [SNOAA35](#) for more information.

### 7.2.5 Power Supply Recommendations

For fast response and comparison applications with noisy or AC inputs, it is recommended to use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation can eat into the comparator's input common mode range and create an inaccurate comparison.

### 7.2.6 Layout

#### 7.2.6.1 Layout Guidelines

For accurate comparator applications without hysteresis it is important maintain a stable power supply with minimized noise and glitches, which can affect the high level input common mode voltage range. To achieve this, it is best to add a bypass capacitor between the supply voltage and ground. This should be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground.

#### 7.2.6.2 Layout Example

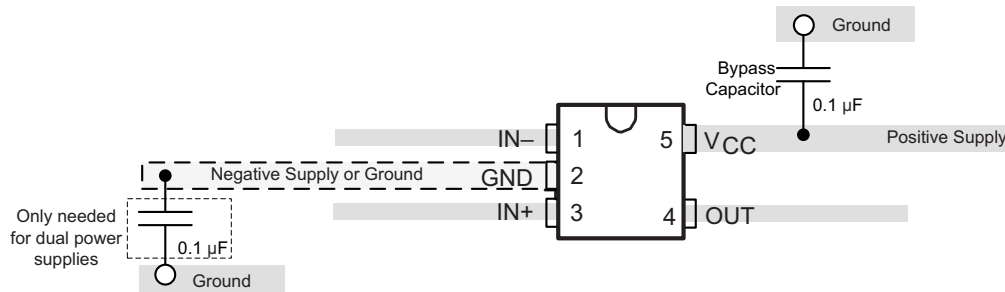


图 7-4. TL331 Layout Example

## 8 Device and Documentation Support

### 8.1 Documentation Support

#### 8.1.1 Related Documentation

[Application Design Guidelines for LM339, LM393, TL331 Family Comparators - SNOAA35](#)

[Analog Engineers Circuit Cookbook: Amplifiers \(See Comparators section\) - SLYY137](#)

[Precision Design, Comparator with Hysteresis Reference Design- TIDU020](#)

[Window comparator circuit - SBOA221](#)

[Reference Design, Window Comparator Reference Design- TIPD178](#)

[Comparator with and without hysteresis circuit - SBOA219](#)

[Inverting comparator with hysteresis circuit - SNOA997](#)

[Non-Inverting Comparator With Hysteresis Circuit - SBOA313](#)

[Zero crossing detection using comparator circuit - SNOA999](#)

[PWM generator circuit - SBOA212](#)

[How to Implement Comparators for Improving Performance of Rotary Encoder in Industrial Drive Applications - SNOAA41](#)

[A Quad of Independently Func Comparators - SNOA654](#)

### 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 8.3 支持资源

TI E2E™ [中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

### 8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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### 8.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 8.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

## 9 Revision History

注：以前版本的页码可能与当前版本的页码不同

<b>Changes from Revision K (September 2023) to Revision L (November 2024)</b>	<b>Page</b>
• Combined thermal table.....	5
• Removed outdated graphs.....	8
• Updated Functional Block Diagram and text.....	14

<b>Changes from Revision J (November 2020) to Revision K (September 2023)</b>	<b>Page</b>
• Added link to application note.....	16

<b>Changes from Revision I (August 2020) to Revision J (November 2020)</b>	<b>Page</b>
• 更正了系列比较表中“B”、“K”和“L”版本的电源电压.....	1

<b>Changes from Revision H (April 2020) to Revision I (August 2020)</b>	<b>Page</b>
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• Added "B" device Typical Char graphs.....	8

<b>Changes from Revision G (January 2015) to Revision H (April 2020)</b>	<b>Page</b>
• 添加了 TL331B 和 TL391B 表和引脚排列，更新了 APL 的新增 B 器件的首页.....	1
• Added Input current, $I_{IK}$ in <i>Absolute Maximum Ratings</i> .....	4
• Changed incorrect TL331 and TL331K Temp Ranges in <i>Recommended Operating Conditions</i> .....	5
• Changed text from: open-drain output to: open-collector output .....	14
• Removed sentence: This is enables much head room for modern day supplies of 3.3V and 5.0V.....	14
• Removed sentence: This is enables much head room for modern day supplies of 3.3V and 5.0V. ....	14
• Changed Output Current specifications from: to: in <i>Design Parameters</i> .....	15
• Changed first paragraph of the <i>Response Time</i> section .....	16
• Added <i>Receiving Notification of Documentation Updates</i> section and <i>Community Resources</i> section.....	18

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TL331BIDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	331B
TL331BIDBVR.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	331B
TL331BIDBVRG4	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	331B
TL331BIDBVRG4.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	331B
<a href="#">TL331IDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	(T1I8, T1IG, T1IL, T1IS)
TL331IDBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(T1I8, T1IG, T1IL, T1IS)
<a href="#">TL331IDBVT</a>	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	(T1I8, T1IG, T1IL, T1IU)
TL331IDBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(T1I8, T1IG, T1IL, T1IU)
TL331IDBVT.B	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(T1I8, T1IG, T1IL, T1IU)
<a href="#">TL331IDBVTG4</a>	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	-40 to 85	T1IG
<a href="#">TL331KDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
TL331KDBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
TL331KDBVR.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
<a href="#">TL331KDBVT</a>	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
TL331KDBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
TL331KDBVT.B	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(T1K8, T1KG, T1KJ, T1KL)
<a href="#">TL391BIDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	391B
TL391BIDBVR.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	391B

(1) **Status:** For more details on status, see our [product life cycle](#).

- (2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- (4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TL331, TL331B, TL391B :**

- Automotive : [TL331-Q1](#), [TL331B-Q1](#), [TL391B-Q1](#)
- Enhanced Product : [TL331-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL331BIDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331BIDBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331KDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331KDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL331KDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL391BIDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL331BIDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TL331BIDBVRG4	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL331IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL331IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL331IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TL331IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TL331KDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL331KDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL331KDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TL391BIDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0



# EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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